5STP 08T2800

Old part no. TV 907C-800-28

Phase Control Thyristor

Properties

- High operational capability
- Possibility of serial and parallel connection

Applications

- Controlled rectifiers
- AC drives

Key Parameters

V_{DRM}, V_{RRM}	=	2 800	V
I_{TAVm}	=	792	A
I_{TSM}	=	10 600	A
V_{TO}	=	1.062	V
r_T	=	0.492	mΩ

Types

	V_{RRM}, V_{DRM}
5STP 08T2800	**2 800 V**
Conditions:	*T_j = -40 ÷ 125 °C, half sine waveform, f = 50 Hz*

Mechanical Data

F_m	**Mounting force**	10 ± 2 kN
m	**Weight**	0.20 kg
D_S	**Surface creepage distance**	13 mm
D_a	**Air strike distance**	8 mm

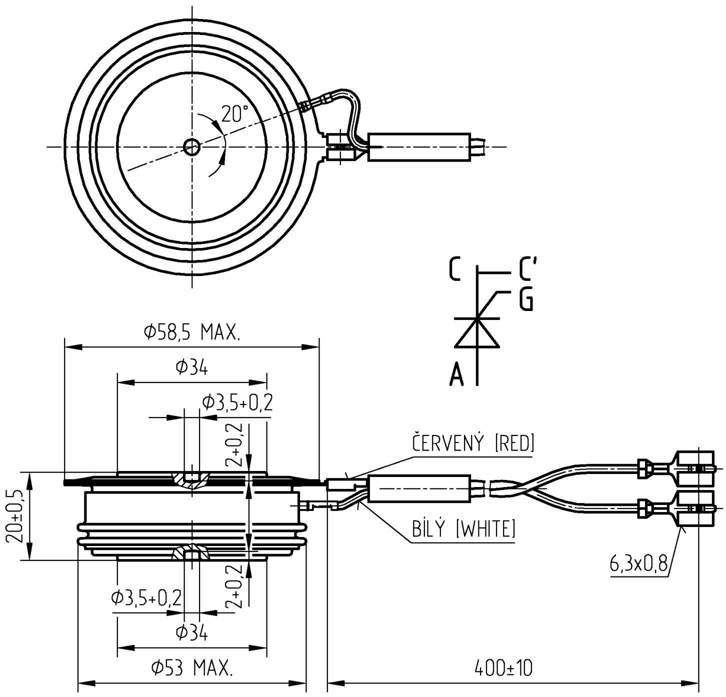

Fig. 1 Case

ABB s.r.o.
Novodvorska 1768/138a, 142 21 Praha 4, Czech Republic
tel.: +420 261 306 250, http://www.abb.com/semiconductors

Maximum Ratings			***Maximum Limits***	***Unit***
V_{RRM} V_{DRM}	**Repetitive peak reverse and off-state voltage** *T_j = -40 ÷ 125 °C*		**2 800**	**V**
I_{TRMS}	**RMS on-state current** *T_c = 70 °C, half sine waveform, f = 50 Hz*		**1 244**	**A**
I_{TAVm}	**Average on-state current** *T_c = 70 °C, half sine waveform, f = 50 Hz*		**792**	**A**
I_{TSM}	**Peak non-repetitive surge** *half sine pulse, V_R = 0 V*	*t_p = 10 ms* *t_p = 8.3 ms*	**10 600** **11 300**	**A**
I^2t	**Limiting load integral** *half sine pulse, V_R = 0 V*	*t_p = 10 ms* *t_p = 8.3 ms*	**561 800** **530 000**	**A^2s**
$(di_T/dt)_{cr}$	**Critical rate of rise of on-state current** *$I_T = I_{TAVm}$, half sine waveform, f = 50 Hz,* *V_D = 2/3 V_{DRM}, t_r = 0.3 µs, I_{GT} = 2 A*		**200**	**A/µs**
$(dv_D/dt)_{cr}$	**Critical rate of rise of off-state voltage** *V_D = 2/3 V_{DRM}*		**1 000**	**V/µs**
P_{GAVm}	**Maximum average gate power losses**		**3**	**W**
I_{FGM}	**Peak gate current**		**10**	**A**
V_{FGM}	**Peak gate voltage**		**12**	**V**
V_{RGM}	**Reverse peak gate voltage**		**10**	**V**
T_{jmin} - T_{jmax}	**Operating temperature range**		**-40 ÷ 125**	**°C**
T_{stgmin} - T_{stgmax}	**Storage temperature range**		**-40 ÷ 125**	**°C**

Unless otherwise specified T_j = 125 °C

Characteristics			***Value***			***Unit***
			min.	***typ.***	***max.***	
V_{TM}	**Maximum peak on-state voltage** I_{TM} = 1 500 A				**1.800**	**V**
V_{T0} r_T	**Threshold voltage** **Slope resistance** I_{T1} = 1 000 A, I_{T2} = 3 000 A				**1.062** **0.492**	**V** **mΩ**
I_{DM}	**Peak off-state current** $V_D = V_{DRM}$				**70**	**mA**
I_{RM}	**Peak reverse current** $V_R = V_{RRM}$				**70**	**mA**
t_{gd}	**Delay time** T_j = 25 °C, V_D = 0.4 V_{DRM}, $I_{TM} = I_{TAVm}$, t_r = 0.3 µs, I_{GT} = 2 A				**2**	**µs**
t_q	**Turn-off time** I_T = 1500 A, di_T/dt = 12.5 A/µs, V_D = 2/3 V_{DRM}, dv_D/dt = 50 V/µs			**200**		**µs**
Q_{rr}	**Recovery charge** *the same conditions as at* t_q			**1 600**		**µC**
I_H	**Holding current**	T_j = 25 °C T_j = 125 °C		**170** **90**		**mA**
I_L	**Latching current**	T_j = 25 °C T_j = 125 °C		**450** **350**		**mA**
V_{GT}	**Gate trigger voltage** V_D = 12V, I_T = 4 A	T_j = - 40 °C T_j = 25 °C T_j = 125 °C	 **0.25**		**4** **3** **2**	**V**
I_{GT}	**Gate trigger current** V_D = 12V, I_T = 4 A	T_j = - 40 °C T_j = 25 °C T_j = 125 °C	 **10**		**500** **250** **150**	**mA**

Unless otherwise specified T_j = 125 °C

Thermal Parameters		***Value***	***Unit***
R_{thjc}	**Thermal resistance junction to case** *double side cooling*	**32.0**	**K/kW**
	anode side cooling	**52.0**	
	cathode side cooling	**83.0**	
R_{thch}	**Thermal resistance case to heatsink** *double side cooling*	**10.0**	**K/kW**
	single side cooling	**20.0**	

Transient Thermal Impedance

Analytical function for transient thermal impedance

$$Z_{thjc} = \sum_{i=1}^{5} R_i (1 - \exp(-t / \tau_i))$$

Conditions:
F_m = 10 ± 2 kN, Double side cooled

Correction for periodic waveforms

180°	**sine:**	**add**	**2.3 K/kW**
180°	**rectangular:**	**add**	**3.1 K/kW**
120°	**rectangular:**	**add**	**5.2 K/kW**
60°	**rectangular:**	**add**	**8.7 K/kW**

i	1	2	3	4	5
τ_i (s)	0.4857	0.2162	0.0762	0.0043	0.0006
R_i(K/kW)	13.07	8.03	8.20	2.57	0.13

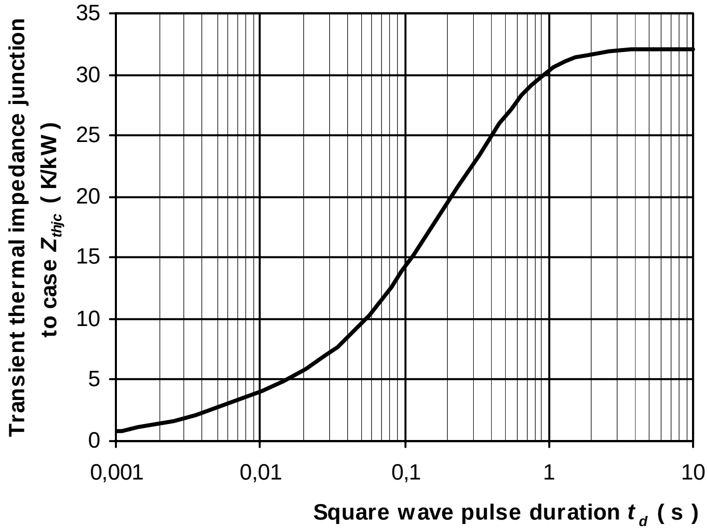

Fig. 2 Dependence transient thermal impedance junction to case on square pulse

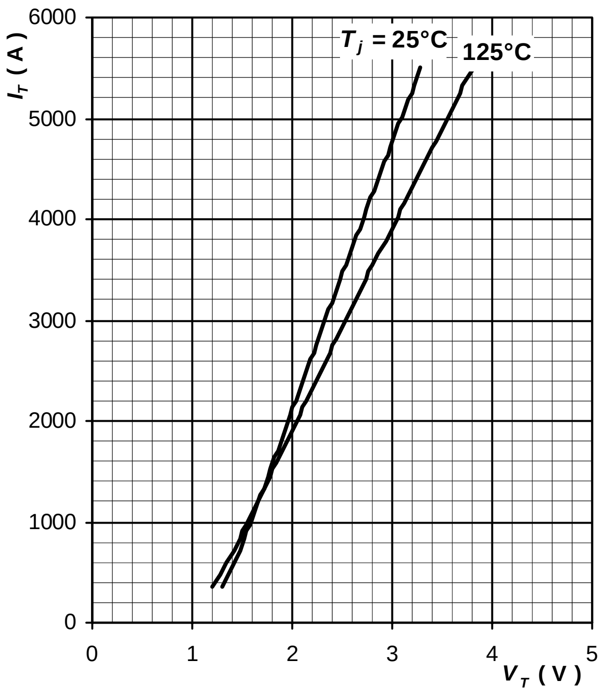

Fig. 3 Maximum on-state characteristics

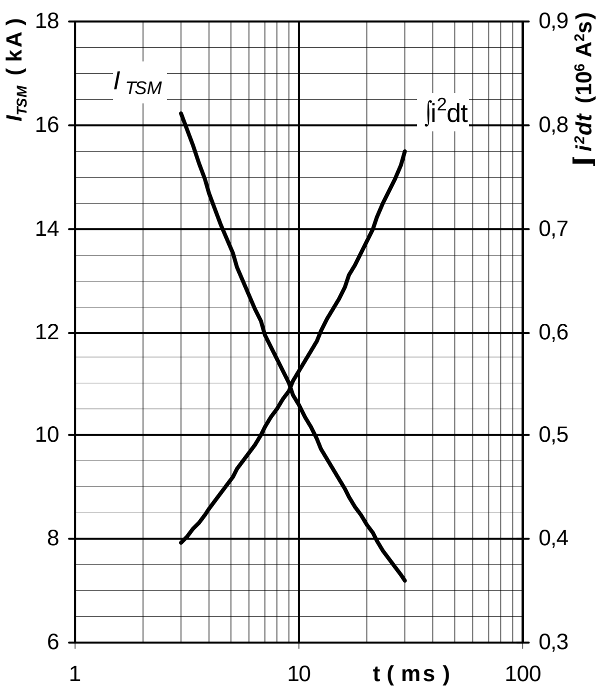

Fig. 4 Surge on-state current vs. pulse length, half sine wave, single pulse, V_R = 0 V, T_j = T_{jmax}

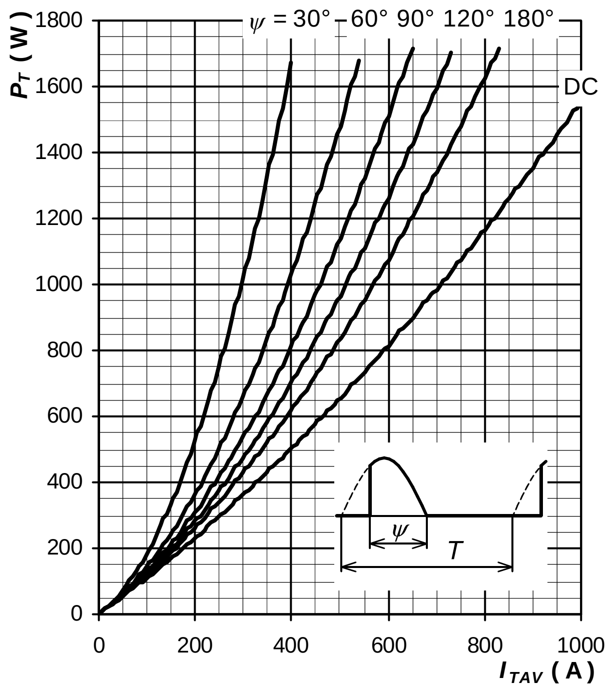

Fig. 5 On-state power loss vs. average on-state current, sine waveform, f = 50 Hz, T = 1/f

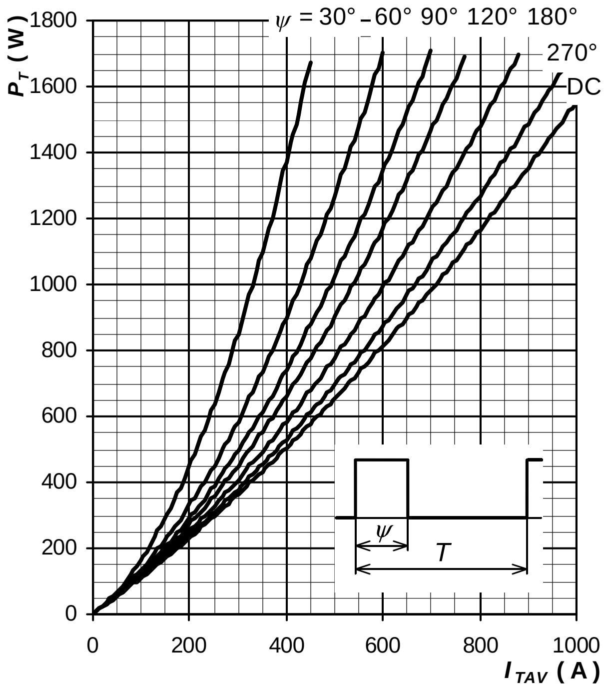

Fig. 6 On-state power loss vs. average on-state current, square waveform, f = 50 Hz, T = 1/f

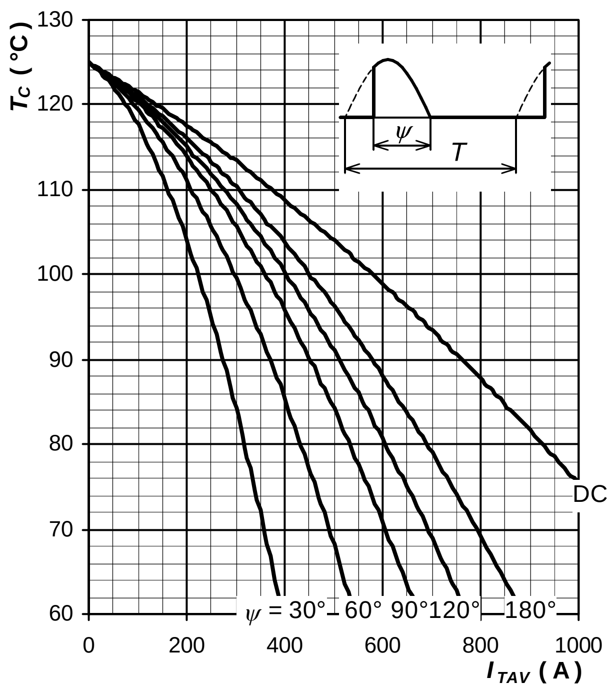

Fig. 7 Max. case temperature vs. aver. on-state current, sine waveform, f = 50 Hz, T = 1/f

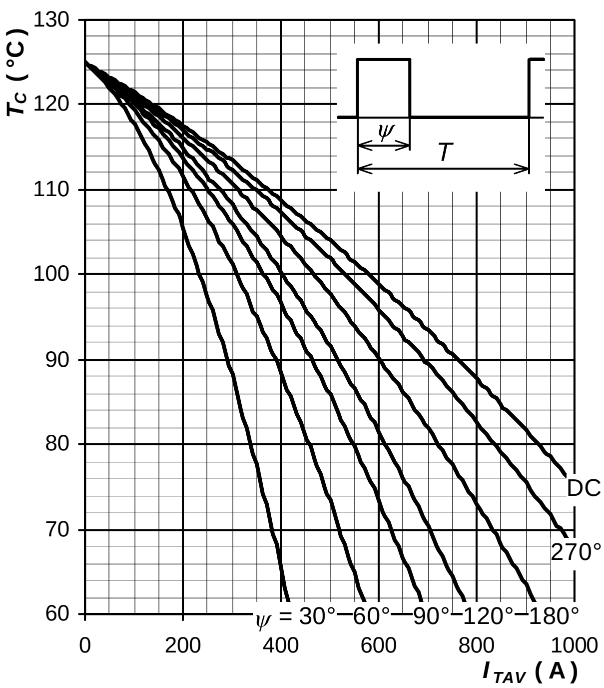

Fig. 8 Max. case temperature vs. aver. on-state current, square waveform, f = 50 Hz, T = 1/f

Notes: